## NSN 5961-01-333-8517

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-333-8517 **Inclosure Material:** Glass **Overall Length:** 7.6 millimeters **Terminal Length:** 26.9 millimeters **Overall Diameter:** 2.7 millimeters **End Application:** 5865-01-188-3309 jamming system, communications, general utility Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-7 **Mounting Method: Terminal Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 3.1 regulator voltage and 3.5 regulator voltage **Current Rating Per Characteristic:** 5.00 milliamperes all primaries horsepower metric **Power Rating Per Characteristic:** 400.0 milliwatts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0